Vishay General Semiconductor

Surface-Mount Ultrafast Plastic Rectifier



Cathode O Anode

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2.0 A				
V _{RRM}	100 V, 150 V, 200 V				
t _{rr}	25 ns				
V_F at $I_F = 2 A$	0.93 V				
T _J max.	175 °C				
Package	SMB (DO-214AA)				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- · Ideal for automated placement
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available - Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer and automotive.

MECHANICAL DATA

Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test. HE3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	ESH2B	ESH2C	ESH2D	UNIT	
Device marking code		EHB	EHC	EHD		
Maximum repetitive peak reverse voltage	V _{RRM}	100	150	200	V	
Maximum RMS voltage	V _{RMS}	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	100	150	200	V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	2.0			A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	60			А	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175			°C	





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ESH2B, ESH2C, ESH2D

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage	I _F = 2 A		V _F ⁽¹⁾	0.93	V	
Maximum DC reverse current		T _A = 25 °C	I_	2.0	μΑ	
at rated DC blocking voltage	Γ	T _A = 125 °C	I _R	50		
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	25	ns	
Typical reverse recovery time	I _F = 2 A, V _R = 30 V,	T _J = 25 °C	- t _{rr}	35	ns	
	dl/dt = 50 A/ μ s, I _{rr} = 10 % I _{RM} T _J = $^{-1}$	T _J = 100 °C		55		
Typical stored charge	F = 2 / 1, TR = 00 T,	T _J = 25 °C	- Q _{rr}	20	nC	
		T _J = 100 °C		35		
Typical junction capacitance	4.0 V, 1 MHz		CJ	30	pF	

Note

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	ESH2B	ESH2C	ESH2D	UNIT	
Typical thermal registeres	R _{0JA} ⁽¹⁾		°C/W			
Typical thermal resistance	R _{θJL} ⁽¹⁾					

Note

 $^{(1)}\,$ Units mounted on PCB with 8.0 mm x 8.0 mm land areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH2D-E3/52T	0.096	52T	750	7" diameter plastic tape and reel		
ESH2D-E3/5BT	0.096	5BT	3200	13" diameter plastic tape and reel		
ESH2DHE3_A/H ⁽¹⁾	0.096	Н	750	7" diameter plastic tape and reel		
ESH2DHE3_A/I (1)	0.096	I	3200	13" diameter plastic tape and reel		

Note

⁽¹⁾ AEC-Q101 qualified



ESH2B, ESH2C, ESH2D

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

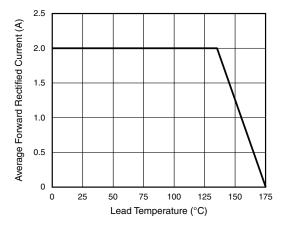


Fig. 1 - Maximum Forward Current Derating Curve

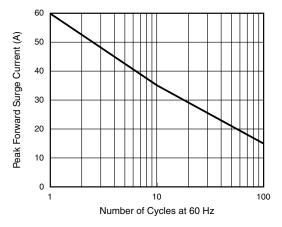


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

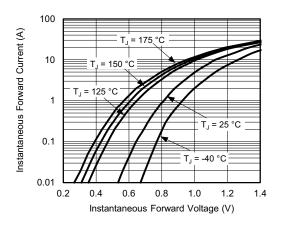


Fig. 3 - Typical Instantaneous Forward Characteristics

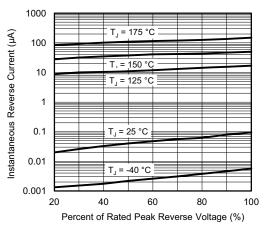


Fig. 4 - Typical Reverse Leakage Characteristics

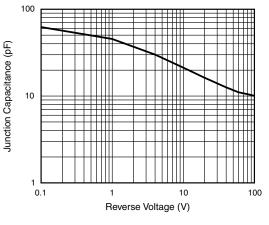


Fig. 5 - Typical Junction Capacitance

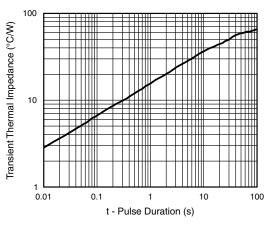


Fig. 6 - Typical Transient Thermal Impedance

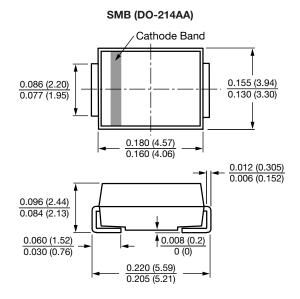
Revision: 13-May-2020 3 Document Number: 84649 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

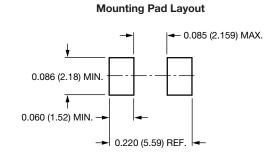


ESH2B, ESH2C, ESH2D

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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